

MUR2040(F)CT

1. Anode 2. Cathode 3. Anode

Ultrafast Recovery Planar Diode Reverse Voltage 400 Volts Forward Current 20 Amperes

Features

- •FRED (Planar) wafer construction
- •Ultrafast recovery time
- Low forward voltage drop, low power losses
- · High efficiency operation

Plastic package has underwriters Laboratory
 Flammability Classification 94V-0





Package: ITO-220-AB

Package: TO-220-AB

Mechanical Data

- Case: Epoxy, Molded
- Weight: 1.9grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 sec
- Shipped 50 units per plastic tube

Maximum Ratings & Electrical Characteristics

(TA=25°C unless otherwise noted)

PARAMETER		TEST		SYMBOL		MUR2040(F)CT	UNIT
		CONDITIONS					
Maximum repetitive peak reverse voltage				VRRM		400	V
Working peak reverse voltage				Vrwm		400	V
Maximum DC blocking voltage				VDC		400	V
Maximum average forward rectified current at				IF(AV)		20	А
T₀=105°C total device per diode						10	
Peak forward surge current 8.3ms single half sine-wave superimposed		IFSM		IFSM		405	А
on rated load per diode						125	
Voltage rate of change (rated V _R)		Г		Dv/dt		10000	V/us
Operating junction temperature range				TJ		—55 to+150	°C
Storage temperature range				Тѕтс		—55 to+150	°C
Maximum Reverse Recover Time		Trr		Trr		50	
(If=0.5Amp, IR=1.0Amp,Irec=0.25Amp)		l irr	1 rr			50	ns
Maximum instantaneous forward voltage per leg		I=10A	Tc=25°C	\/-		1.50	V
		I _F =10A	Tc=125℃	VF		1.40	V
Maximum reverse current per leg at working peak			TJ=25℃			10	uA
Reverse voltage			TJ=100°C	l _R		500	uA
	Thermal Characteristics TA	= 25℃ unl	ess otherwi	se no	ted	I	
Symbol	Parameter	TYP (TO		TYP (ITO-220-AB)		Unit	
RθJC	Thermal Resistance, Junction to Case per Leg	2.0		4.0	°C /W		
RθJA	Thermal Resistance, Junction to Ambient per Leg	62.5			62.5		

Note: Pulse test:300us pulse width, duty cycle=2%



Reverse Voltage 400 Volts Forward Current 20 Amperes

Ratings and Characteristics Curves

(T_A = 25^oC unless otherwise noted)

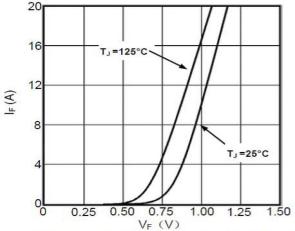


Fig1. Forward Voltage Drop vs Forward Current

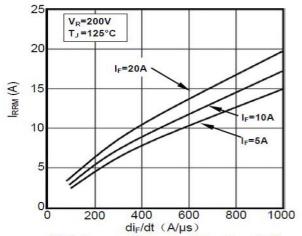


Fig3. Reverse Recovery Current vs di_F/dt

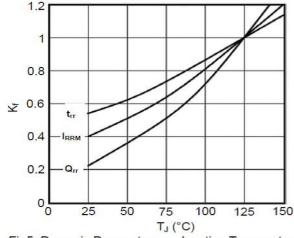


Fig5. Dynamic Parameters vs Junction Temperature

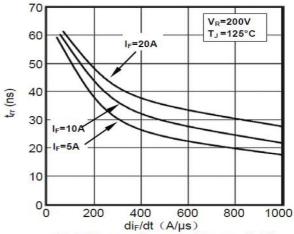


Fig2. Reverse Recovery Time vs di_F/dt

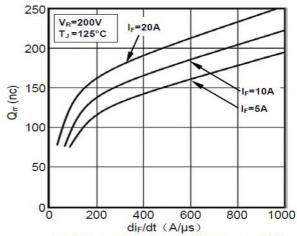
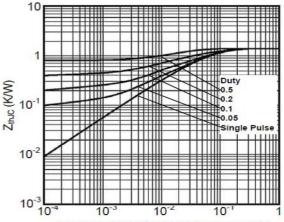


Fig4. Reverse Recovery Charge vs di_F/dt



Rectangular Pulse Duration (seconds) Fig6. Transient Thermal Impedance



* Epoxy width 10.0±0.2

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10.10±0.2

Package Outline Dimensions

Unit: millimeters

